# BCR5LM-12RB

## 600V - 5A - Triac
## Medium Power Use

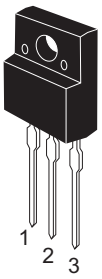
R07DS0969EJ0100
Rev.1.00
Dec 20, 2012

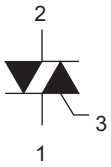
### Features

- $I_{T\ (RMS)}$ : 5 A
- $V_{DRM}$ : 600 V
- $I_{FGTI}$, $I_{RGTI}$, $I_{RGTIII}$: 15 mA
- Viso: 1800 V
- Insulated Type
- Tj: 150 °C
- Planar Passivation Type
- UL Recognized: File No. E223904

### Outline

RENESAS Package code: PRSS0003AF-A)
(Package name: TO-220FL)




1. $T_1$ Terminal
2. $T_2$ Terminal
3. Gate Terminal

### Applications

Electric rice cooker, electric pot, and other heater control

### Maximum Ratings

| Parameter | Symbol | Voltage class | Unit |
|---|---|---|---|
| | | 12 | |
| Repetitive peak off-state voltage[Note1] | $V_{DRM}$ | 600 | V |
| Non-repetitive peak off-state voltage[Note1] | $V_{DSM}$ | 720 | V |

| Parameter | Symbol | Ratings | Unit | Conditions |
|---|---|---|---|---|
| RMS on-state current | $I_{T\ (RMS)}$ | 5 | A | Commercial frequency, sine full wave 360° conduction, Tc = 122°C |
| Surge on-state current | $I_{TSM}$ | 50 | A | 60 Hz sine wave 1 full cycle, peak value, non-repetitive |
| $I^2t$ for fusion | $I^2t$ | 10.4 | $A^2s$ | Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current |
| Peak gate power dissipation | $P_{GM}$ | 3 | W | |
| Average gate power dissipation | $P_{G\ (AV)}$ | 0.3 | W | |
| Peak gate voltage | $V_{GM}$ | 10 | V | |
| Peak gate current | $I_{GM}$ | 2 | A | |
| Junction Temperature | Tj | –40 to +150 | °C | |
| Storage temperature | Tstg | –40 to +150 | °C | |
| Mass | — | 1.5 | g | Typical value |
| Isolation voltage [Note4] | Viso | 1800 | V | Ta = 25°C, AC 1 minute $T_1$ • $T_2$ • G terminal to case |

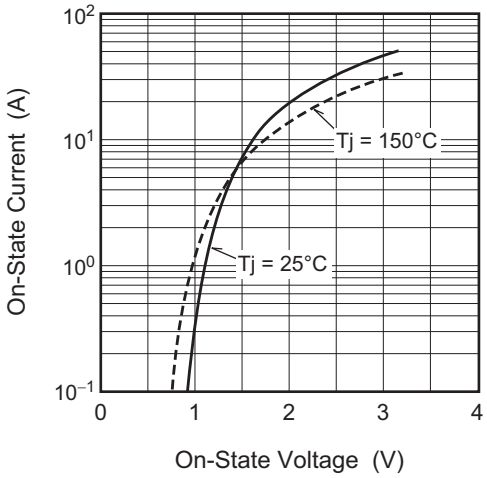
## Electrical Characteristics

| Parameter | | Symbol | Rated value | | | Unit | Test conditions |
|---|---|---|---|---|---|---|---|
| | | | Min. | Typ. | Max. | | |
| Repetitive peak off-state current | | $I_{DRM}$ | — | — | 2.0 | mA | Tj = 150°C, $V_{DRM}$ applied |
| On-state voltage | | $V_{TM}$ | — | — | 1.5 | V | Tc = 25°C, $I_{TM}$ = 7A, instantaneous measurement |
| Gate trigger voltage[Note2] | I | $V_{FGTI}$ | — | — | 1.5 | V | Tj = 25°C, $V_D$ = 6 V, $R_L$ = 6 Ω, $R_G$ = 330 Ω |
| | II | $V_{RGTI}$ | — | — | 1.5 | V | |
| | III | $V_{RGTIII}$ | — | — | 1.5 | V | |
| Gate trigger curent[Note2] | I | $I_{FGTI}$ | — | — | 15 | mA | Tj = 25°C, $V_D$ = 6 V, $R_L$ = 6 Ω, $R_G$ = 330 Ω |
| | II | $I_{RGTI}$ | — | — | 15 | mA | |
| | III | $I_{RGTIII}$ | — | — | 15 | mA | |
| Gate non-trigger voltage | | $V_{GD}$ | 0.2 | — | — | V | Tj = 125°C, $V_D$ = 1/2 $V_{DRM}$ |
| | | | 0.1 | — | — | V | Tj = 150°C, $V_D$ = 1/2 $V_{DRM}$ |
| Thermal resistance | | $R_{th\ (j-c)}$ | — | — | 4.9 | °C/W | Junction to case[Note3] |

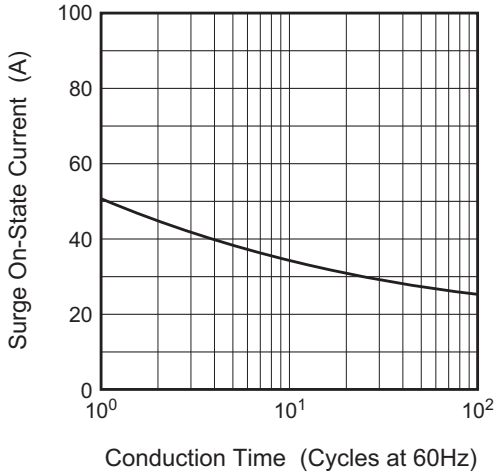
Notes: 1. Gate open.
2. Measurement using the gate trigger characteristics measurement circuit
3. The contact thermal resistance $R_{th\ (c-f)}$ in case of greasing is 0.5°C/W.
4. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

## Main Characteristics

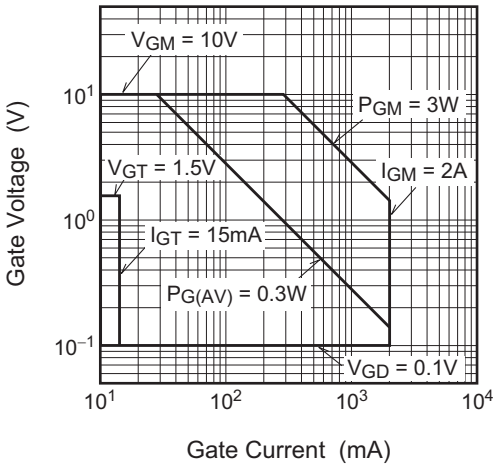
Maximum On-State Characteristics



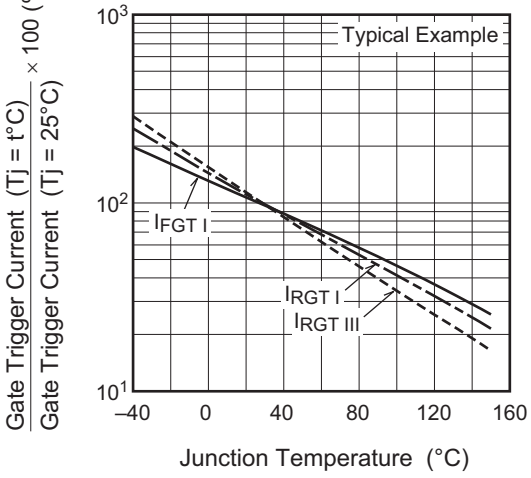

Rated Surge On-State Current



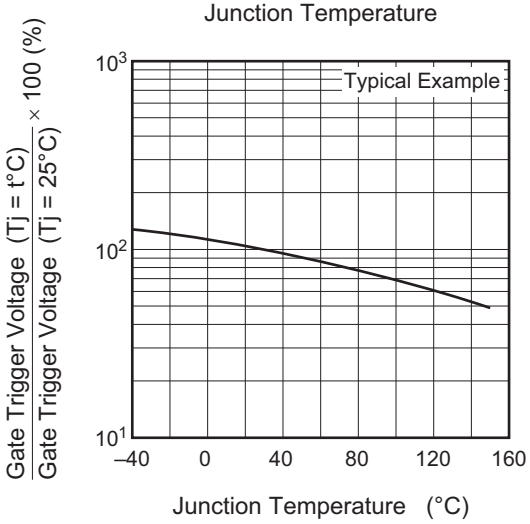

Gate Characteristics (I, II and III)



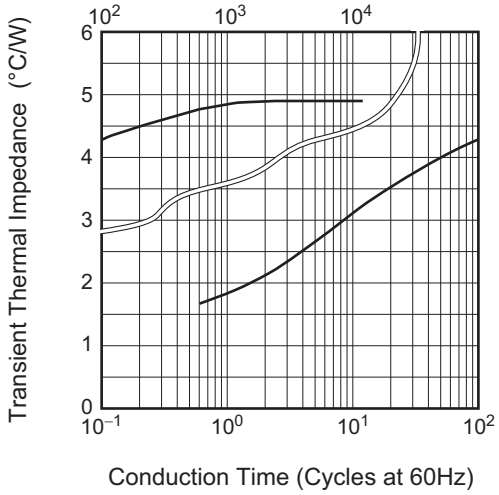

Gate Trigger Current vs. Junction Temperature



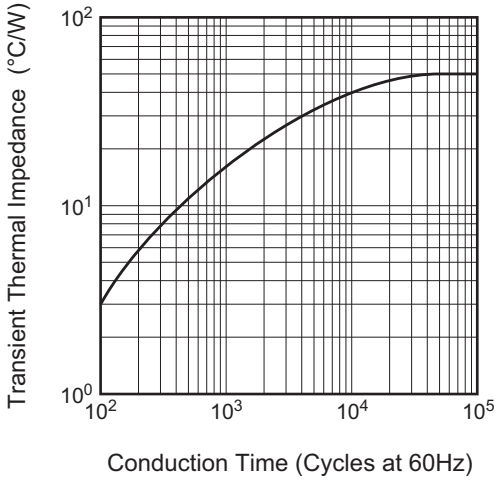

Gate Trigger Voltage vs. Junction Temperature



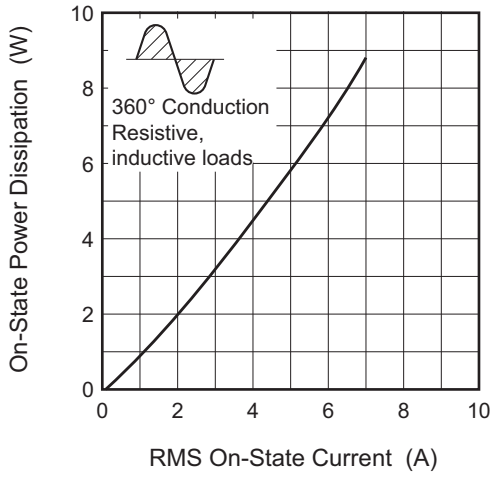

Maximum Transient Thermal Impedance Characteristics (Junction to case)



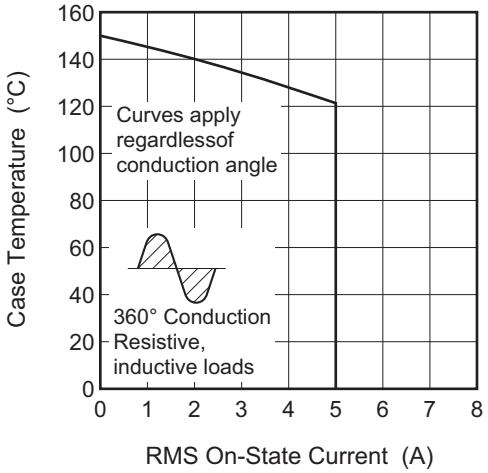
Maximum Transient Thermal Impedance Characteristics (Junction to ambient)



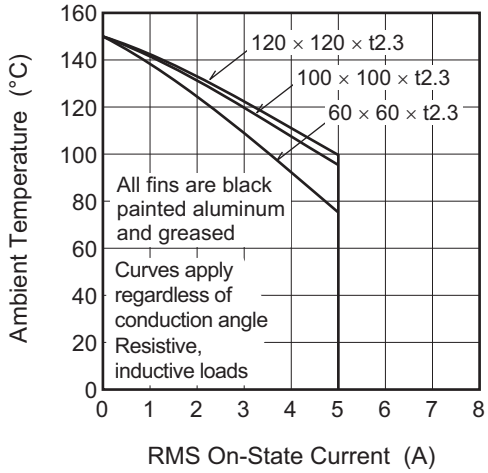

Maximum On-State Power Dissipation



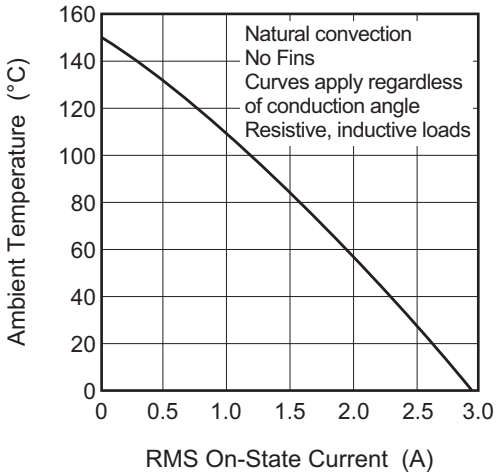

Allowable Case Temperature vs. RMS On-State Current



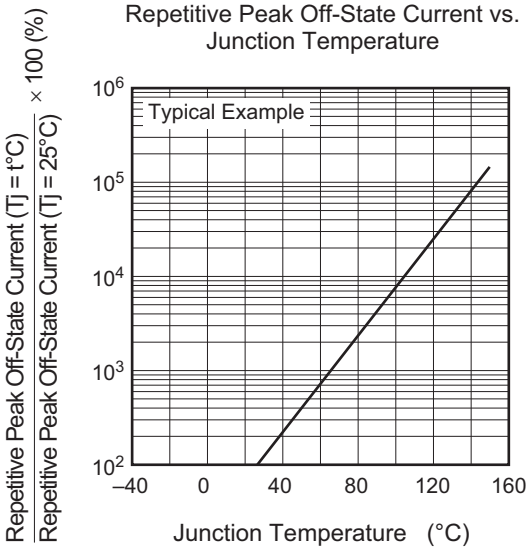

Allowable Ambient Temperature vs. RMS On-State Current



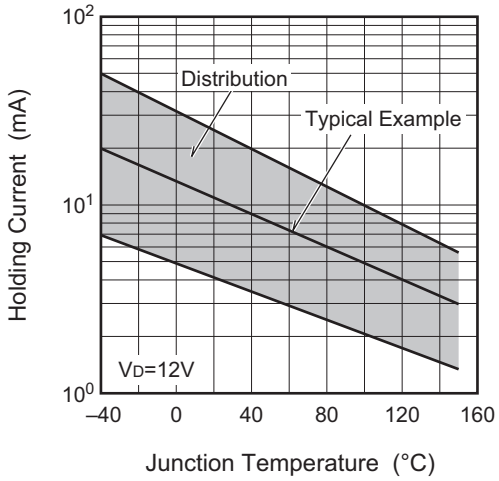

Allowable Ambient Temperature vs. RMS On-State Current



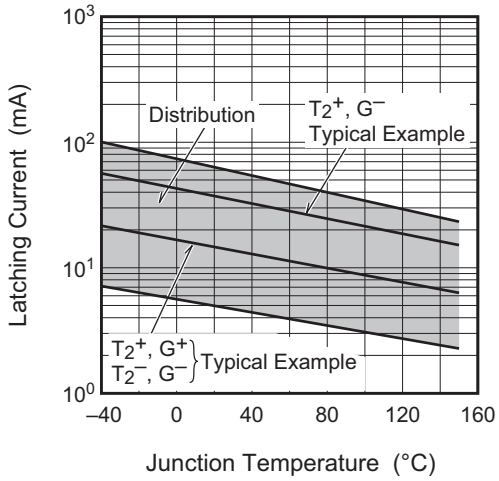

Repetitive Peak Off-State Current vs. Junction Temperature



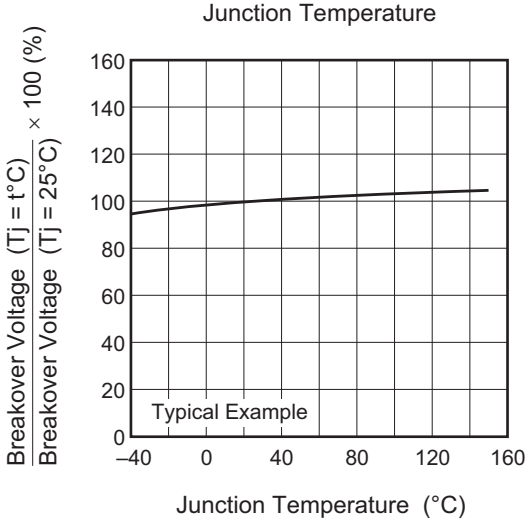
Holding Current vs.
Junction Temperature



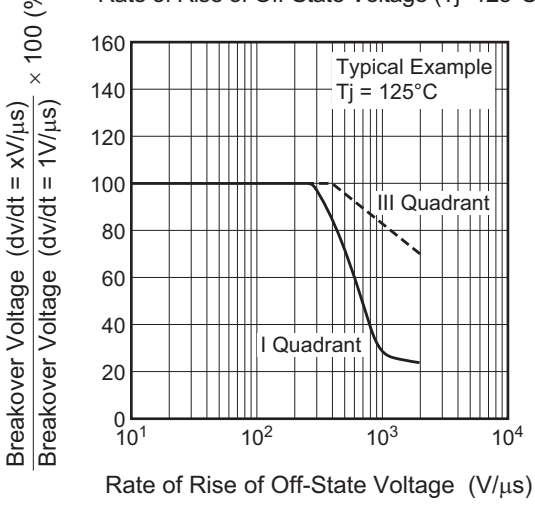

Latching Current vs.
Junction Temperature



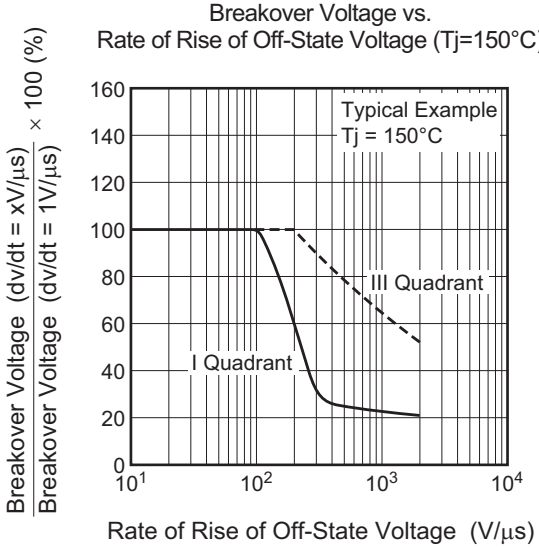

Breakover Voltage vs.
Junction Temperature



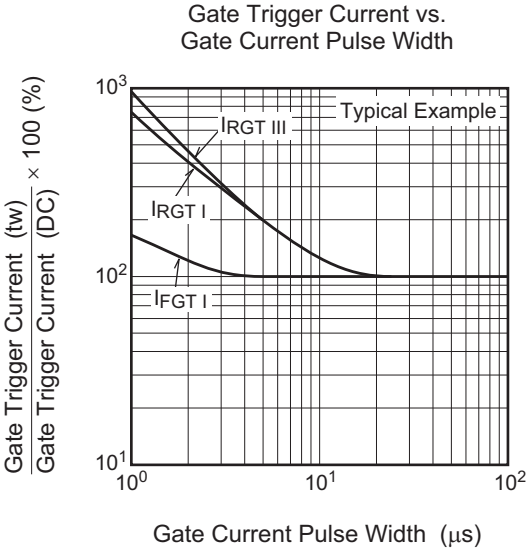

Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=125°C)



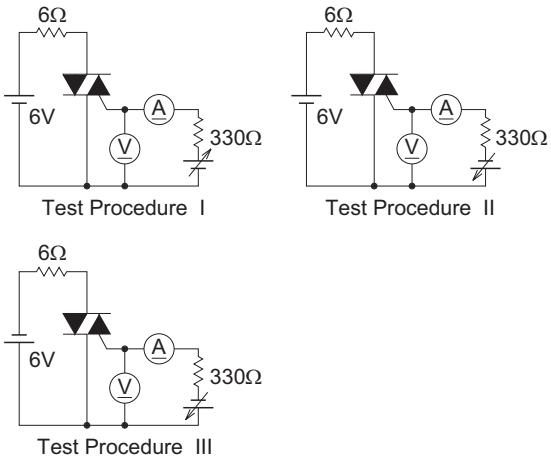

Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=150°C)



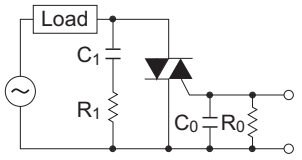

Gate Trigger Current vs.
Gate Current Pulse Width



Gate Trigger Characteristics Test Circuits




Recommended Circuit Values Around The Triac

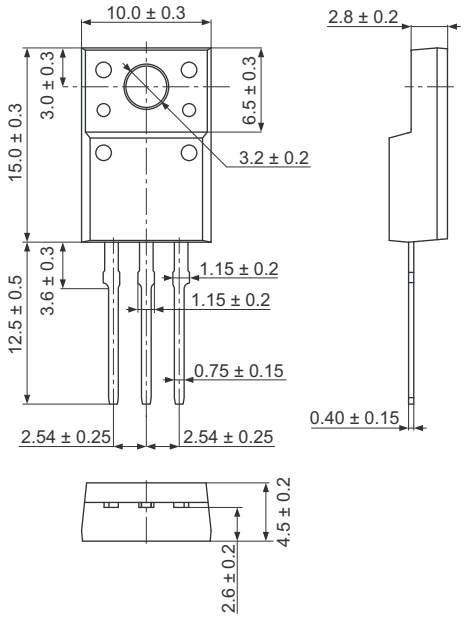



$C_1$ = 0.1 to 0.47μF $C_0$ = 0.1μF
$R_1$ = 47 to 100Ω $R_0$ = 100Ω

## Package Dimensions

| Package Name | JEITA Package Code | RENESAS Code | Previous Code | MASS[Typ.] |
|---|---|---|---|---|
| TO-220FL | — | PRSS0003AF-A | TO-220FL | 1.5g |

Unit: mm




## Ordering Information

| Orderable Part Number | Packing | Quantity | Remark |
|---|---|---|---|
| BCR5LM-12RB#B00 | Tube | 50 pcs. | Straight type |
| BCR5LM-12RB-A8#B00 | Tube | 50 pcs. | A8 Lead form |

Note: Please confirm the specification about the shipping in detail.

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**Renesas Electronics America Inc.**
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

**Renesas Electronics Canada Limited**
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

**Renesas Electronics Europe Limited**
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

**Renesas Electronics Europe GmbH**
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

**Renesas Electronics Hong Kong Limited**
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

**Renesas Electronics Taiwan Co., Ltd.**
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

**Renesas Electronics Singapore Pte. Ltd.**
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

**Renesas Electronics Malaysia Sdn.Bhd.**
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Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

**Renesas Electronics Korea Co., Ltd.**
11F., Samik Lavied' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141



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